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## LED ARRAY

**LA15B/GHV5-W37**

## DATA SHEET

DOC. NO : QW0905-LA15B/GHV5-W37

REV. : A

DATE : 06 - Apr - 2005



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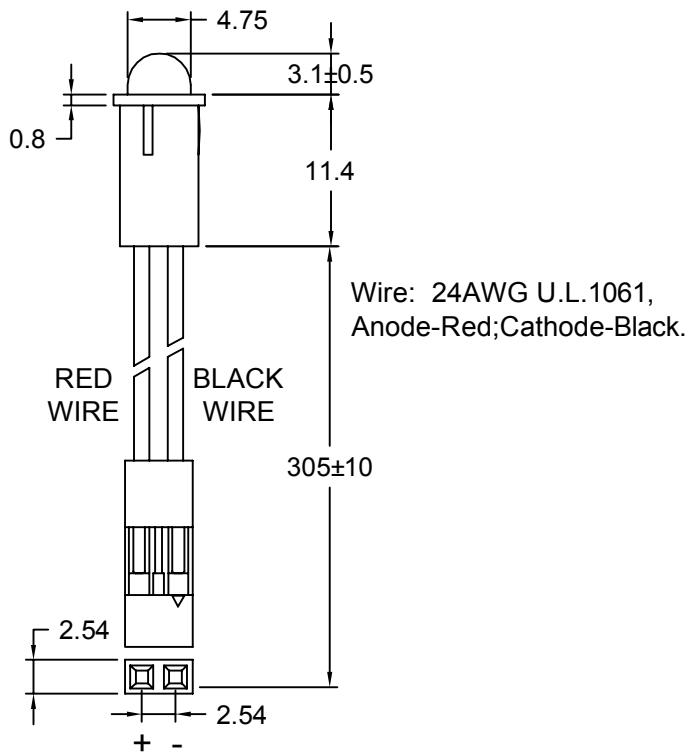
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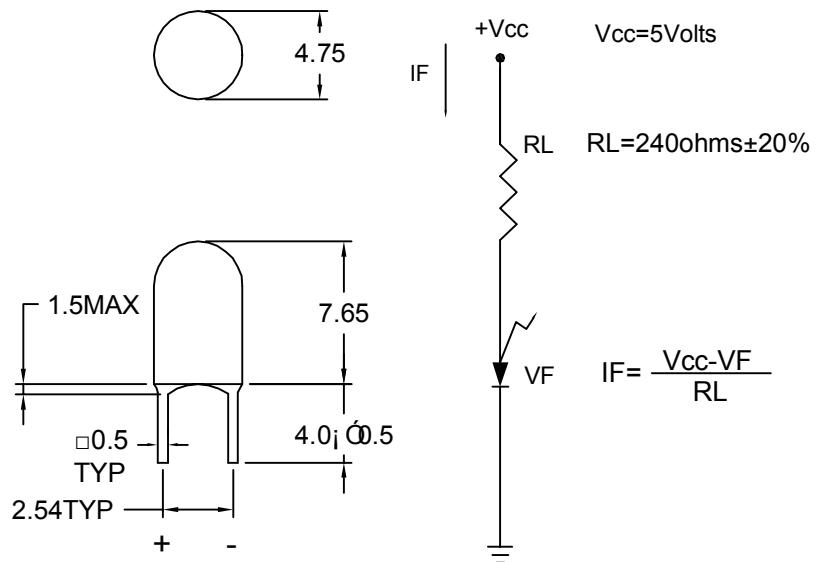
PART NO. LA15B/GHV5-W37

Page 1/4

### Package Dimensions



### LG3133/S43



Note : 1.All dimension are in millimeter tolerance is ±0.25mm unless otherwise noted.  
2.Specifications are subject to change without notice.



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PART NO. LA15B/GHV5-W37

Page 2/4

## Absolute Maximum Ratings at Ta=25

Parameter	Symbol	Absolute Maximum Ratings		<b>UNIT</b>
		G		
Forward Voltage	V <sub>F</sub>	5		V
Reverse Voltage	V <sub>R</sub>	8		V
Operating Temperature	T <sub>opr</sub>	-40 ~ +85		
Storage Temperature	T <sub>stg</sub>	-40 ~ +100		

## Typical Electrical &amp; Optical Characteristics (Ta=25 )

PART NO	MATERIAL	COLOR		Peak wave length Pnm	Spectral halfwidth nm	Forward current (mA) @5V		Luminous intensity (mcd) @5V		Reverse current ( $\mu$ A) VR=5V	Viewing angle 2 1/2 (deg)
		Emitted	Lens			Min.	Max.	Min.	Typ.		
LA15B/GHV5-W37	GaP	Green	Water Clear	565	30	8	20	10	18	100	50

Note : 1.The forward voltage data did not including  $\pm 0.1V$  testing tolerance.  
 2. The luminous intensity data did not including  $\pm 15\%$  testing tolerance.



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PART NO. LA15B/GHV5-W37

Page 3/4

### Typical Electro-Optical Characteristics Curve

G CHIP

Fig.1 Forward current vs. Forward Voltage

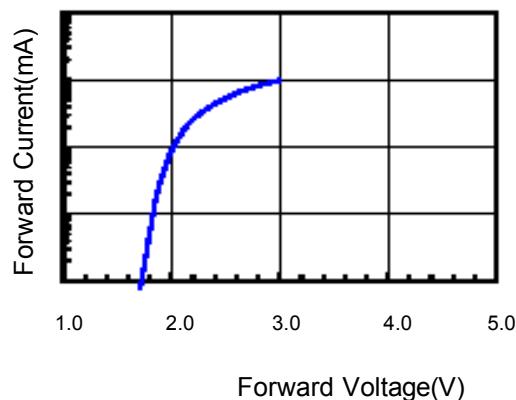


Fig.2 Relative Intensity vs. Forward Current

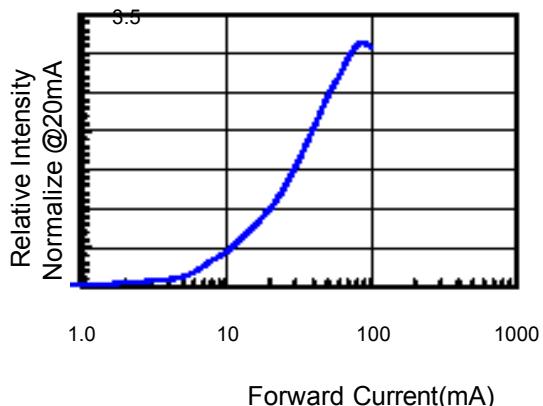


Fig.3 Forward Voltage vs. Temperature

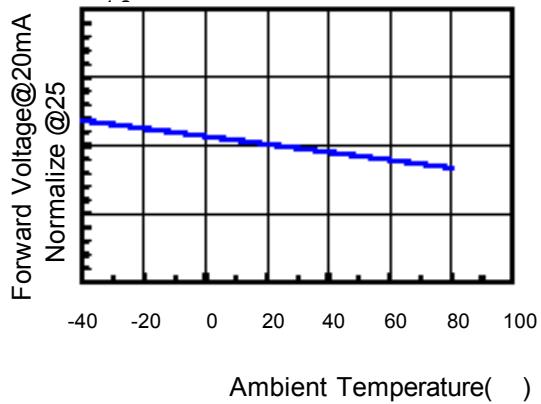


Fig.4 Relative Intensity vs. Temperature

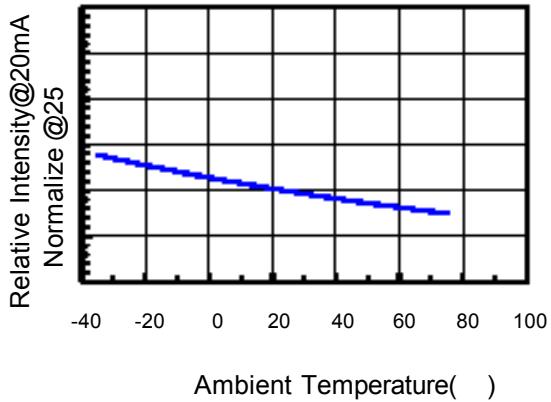
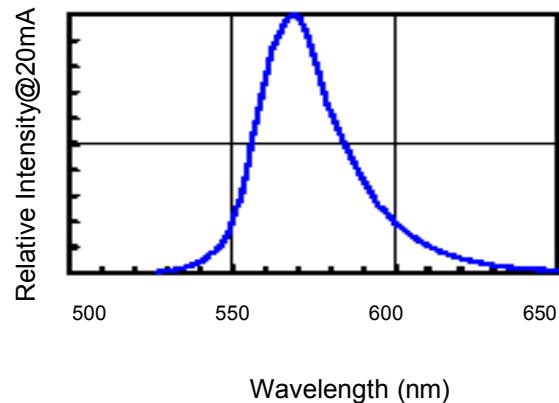


Fig.5 Relative Intensity vs. Wavelength





## Reliability Test:

Test Item	Test Condition	Description	Reference Standard
Operating Life Test	1.Under Room Temperature 2.If=20mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of determining the resistance of a part in electrical and thermal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1
High Temperature Storage Test	1.Ta=105 ±5 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10
Low Temperature Storage Test	1.Ta=-40 ±5 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12
High Temperature High Humidity Test	1.Ta=65 ±5 2.RH=90 %~95 % 3.t=240hrs ±2hrs	The purpose of this test is the resistance of the device under tropical for hours.	MIL-STD-202:103B JIS C 7021: B-11
Thermal Shock Test	1.Ta=105 ±5 &-40 ±5 (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011